

## CORRECTION

[View Article Online](#)  
[View Journal](#) | [View Issue](#)



## Correction: Solvent-free vacuum growth of oriented HKUST-1 thin films

Cite this: *J. Mater. Chem. A*, 2020, **8**, 1483

Sungmin Han,<sup>a</sup> Ryan A. Ciufo,<sup>a</sup> Melissa L. Meyerson,<sup>a</sup> Benjamin K. Keitz<sup>b</sup> and C. Buddie Mullins<sup>\*abc</sup>

DOI: 10.1039/c9ta90298h

Correction for 'Solvent-free vacuum growth of oriented HKUST-1 thin films' by Sungmin Han *et al.*, *J. Mater. Chem. A*, 2019, **7**, 19396–19406.

[rsc.li/materials-a](https://rsc.li/materials-a)

The authors regret a labelling error in Fig. 4(b); a peak labelled '300' in the published article should instead have been labelled '400'. Moreover, on page 19401, the phrase '(200) and (300) planes' should instead have read '(200) and (400) planes'.

A corrected version of Fig. 4 can be found below.



<sup>a</sup>Department of Chemistry, University of Texas at Austin, Austin, Texas 78712-0231, USA. E-mail: [mullins@che.utexas.edu](mailto:mullins@che.utexas.edu)

<sup>b</sup>McKetta Department of Chemical Engineering, University of Texas at Austin, Austin, Texas 78712-0231, USA

<sup>c</sup>Center for Nano and Molecular Science and Technology, Texas Materials Institute, Center for Electrochemistry, University of Texas at Austin, Austin, Texas 78712-0231, USA

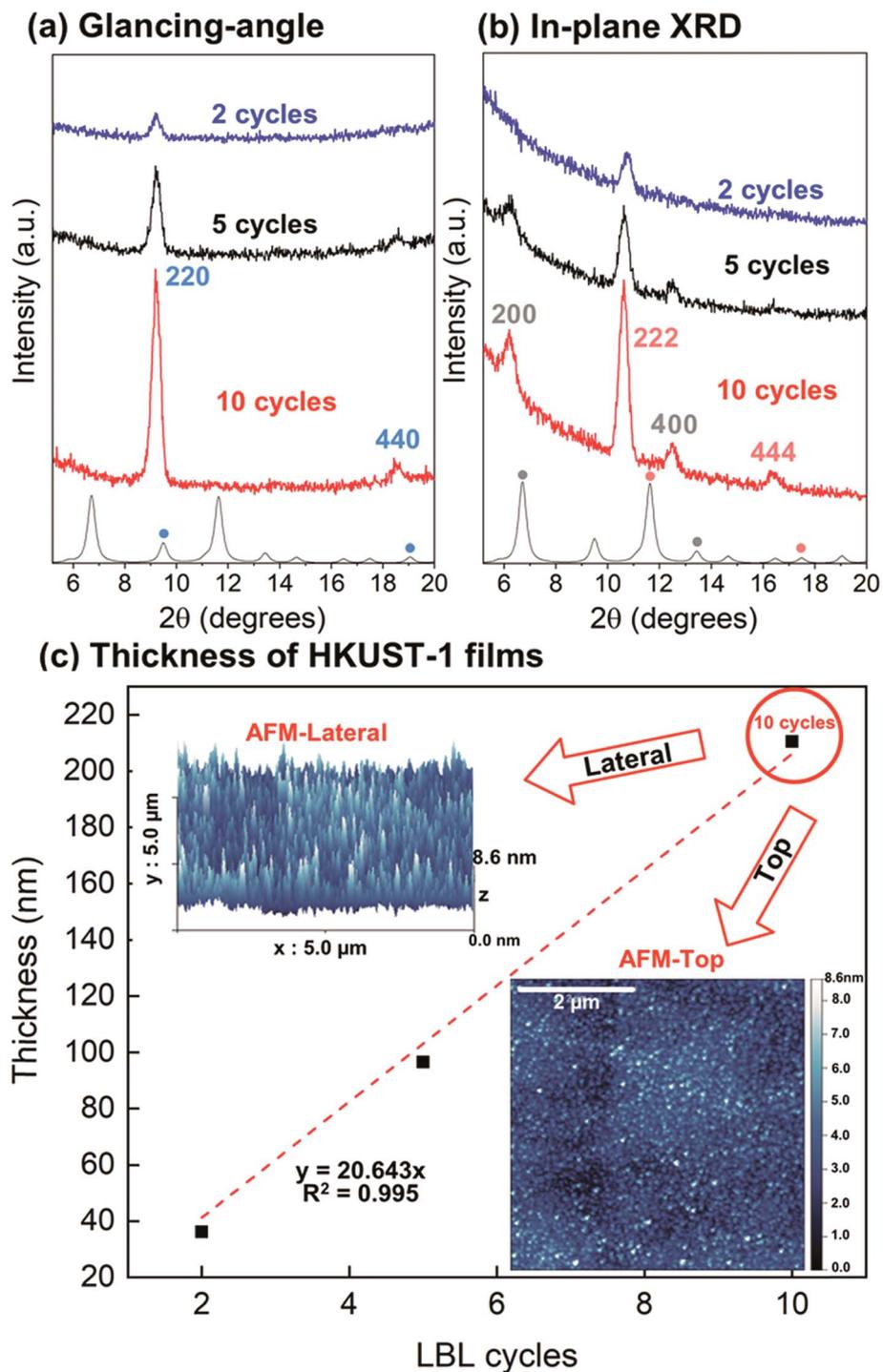


Fig. 4 (a) The glancing-angle and (b) the in-plane XRD measurements for 2, 5, 10 LBL cycles of HKUST-1 thin films with simulated HKUST-1 XRD patterns (black lines at the bottom of each figure). (c) shows the thickness of these HKUST-1 thin films measured by AFM. Top and lateral views of the 10 cycled HKUST-1 film are also included as insets.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

